NSN 5961-01-368-9744

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-368-9744 **Inclosure Material:** Plastic **Overall Length:** Between 0.120 inches and 0.300 inches **Terminal Length:** Between 1.000 inches and 1.500 inches **Overall Diameter:** Between 0.060 inches and 0.107 inches Joint Electronic Device Engineering Council/jedec/case Outline Designation: Do-7 **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 8.55 regulator voltage, dc and 9.45 regulator voltage, dc **Current Rating Per Characteristic:** 10.00 microamperes collector current, dc peak **Power Rating Per Characteristic:** 500.0 milliwatts any acceptable preset **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius ambient air **Test Data Document:** 81349-mil-c-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Terminal Type And Quantity:** 2 uninsulated wire lead **Specification Data:** 81349-mil-c-19500/156 government specification Shelf Life: N/a **Unit Of Measure: Demilitarization:** No